Refine Search

Search Results -

Terms	Documents
semiconductor and (((trench or groove) near3 fill) same liquid)	1

US Pre-Grant Publication Full-Text Database
US Patents Full-Text Database
US OCR Full-Text Database
EPO Abstracts Database
JPO Abstracts Database
Derwent World Patents Index
IBM Technical Disclosure Bulletins

Search:

Database:

		Refine Search
Recall Text	Clear	Interrupt

Search History

DATE: Tuesday, July 19, 2005 Printable Copy Create Case

Set Name side by side	Query	<u>Hit</u> Count	Set Name result set
DB=	TDBD; PLUR=YES; OP=ADJ		
<u>L22</u>	semiconductor and (((trench or groove) near3 fill) same liquid)	1	<u>L22</u>
DB =	DWPI; PLUR=YES; OP=ADJ		
<u>L21</u>	semiconductor and (((trench or groove) near3 fill) same liquid)	17	<u>L21</u>
DB =	JPAB; PLUR=YES; OP=ADJ		
<u>L20</u>	semiconductor and (((trench or groove) near3 fill) same liquid)	22	<u>L20</u>
DB =	EPAB; PLUR=YES; OP=ADJ		
<u>L19</u>	semiconductor and (((trench or groove) near3 fill) same liquid)	0	<u>L19</u>
DB =	USPT; PLUR=YES; OP=ADJ		
<u>L18</u>	semiconductor and (((trench or groove) near3 fill) same liquid)	150	<u>L18</u>
DB =	PGPB; PLUR=YES; OP=ADJ		
<u>L17</u>	semiconductor and (((trench or groove) near3 fill) same liquid)	95	<u>L17</u>
<u>L16</u>	20040266153	1	<u>L16</u>
<u>L15</u>	20040209484	1	<u>L15</u>
<u>L14</u>	20030129826	1	<u>L14</u>
<u>L13</u>	20030032281	1	<u>L13</u>

WEST I	Refine Search	Pag	ge 2 of 2
<u>L12</u>	200300322281	0	<u>L12</u>
<u>L11</u>	20020018849	1	<u>L11</u>
<u>L10</u>	20020000195	1	<u>L10</u>
<u>L9</u>	20010041250	1	<u>L9</u>
<u>L8</u>	2001/0041250	0	<u>L8</u>
DB =	DWPI; PLUR=YES; OP=ADJ		
<u>L7</u>	2001/0041250	0	<u>L7</u>
DB = 0	JPAB; PTVR=YES; OP=ADJ		
<u>L6</u>	(self aligned) and silicide and (SiGe or (silicon adj germanium)) and metal and ((the sal or heat\$) near3 anneal\$)	0	<u>L6</u>
DB = 1	EPAB; PLU: YES; OP=ADJ		
<u>L5</u>	(self aligned, and silicide and (SiGe or (silicon adj germanium)) and metal and ((thermal heat\$) near3 anneal\$)	0	<u>L5</u>
DB =	USPT; PLUR=YE QP=ADJ		
<u>L4</u>	(self aligned) and \$ side and (SiGe or (silicon adj germanium)) and metal and ((thermal or hear near3 anneal\$)	322	<u>L4</u>
DB = 0	PGPB; PLUR=YES; OP DJ		
<u>L3</u>	(self aligned) and silicide (SiGe or (silicon adj germanium)) and metal and ((thermal or heat\$) nears oneal\$)	246	<u>L3</u>
DB =	TDBD; PLUR=YES; OP=ADJ		
<u>L2</u>	(self aligned) and silicide and (SiC or (silicon adj germanium)) and metal and ((thermal or heat\$) near3 anneal	1	<u>L2</u>
DB = 1	DWPI; PLUR=YES; OP=ADJ		
<u>L1</u>	(self aligned) and silicide and (SiGe or (sih padj germanium)) and metal and ((thermal or heat\$) near3 anneal\$)	3	<u>L1</u>

END OF SEARCH HISTORY

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0	(isolation adj trench) and (liquid adj deposition) and (solid adj deposition)". clm"	USPAT	ADJ	ON	2005/07/19 14:17
L2	1419	(438/424,427,431).CCLS.	USPAT	OR	OFF	2005/07/19 14:17